Preferred Device

Surface Mount Ultrafast Power Rectifiers

Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes in surface mount applications where compact size and weight are critical to the system.

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- High Temperature Glass Passivated Junction
- Low Forward Voltage Drop (0.77 Volts Max @ 2.0 A, TJ = 150°C)

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 95 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 12 mm Tape and Reel, 2500 units per reel
- Polarity: Polarity Band Indicates Cathode Lead
- Marking: U2D

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V _{RRM} V _{RWM} V _R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	200	Volts
lF(AV)	F(AV) Average Rectified Forward Current		Amps
IFSM	Non–Repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	40	Amps
Тј	Operating Junction Temperature	– 65 to +175	°C



ON Semiconductor

http://onsemi.com

ULTRAFAST RECTIFIERS 2 AMPERES 200 VOLTS



CASE 403A

MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping	
MURS220T3	SMB	2500 Tape & Reel	

Preferred devices are recommended choices for future use and best overall value.

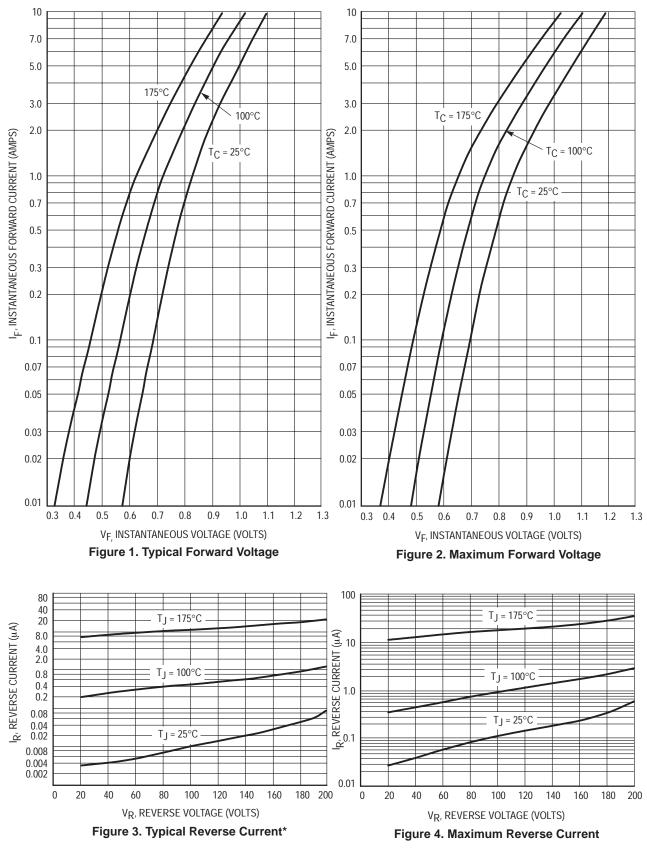
THERMAL CHARACTERISTICS

Symbol	Characteristic	Value	Unit
R _{θJL}	Thermal Resistance, Junction to Lead $(T_L = 25^{\circ}C)$	13	°C/W

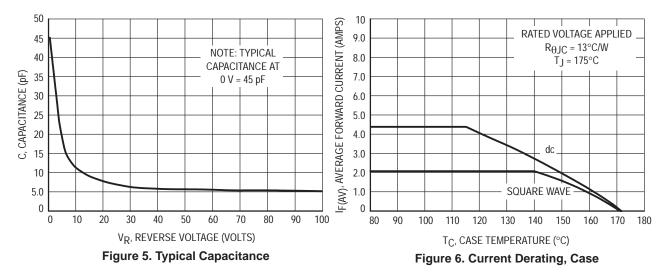
ELECTRICAL CHARACTERISTICS

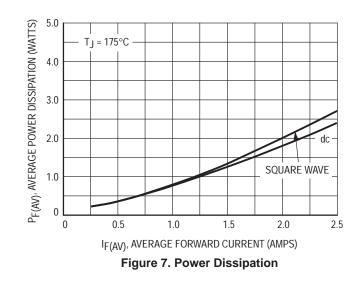
Symbol	Characteristic	Value	Unit
٧F	Maximum Instantaneous Forward Voltage (Note NO TAG) ($i_F = 2.0 \text{ A}, T_J = 25^{\circ}\text{C}$) ($i_F = 2.0 \text{ A}, T_J = 150^{\circ}\text{C}$)	0.95 0.77	Volts
İR	Maximum Instantaneous Reverse Current (Note NO TAG) (Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 150^{\circ}C$)	2.0 50	μΑ
t _{rr}	Maximum Reverse Recovery Time ($i_F = 1.0 \text{ A}$, di/dt = 50 A/µs) ($i_F = 0.5 \text{ A}$, $i_R = 1.0 \text{ A}$, I_R to 0.25 A)	35 25	ns
t _{fr}	Maximum Forward Recovery Time (i _F = 1.0 A, di/dt = 100 A/μs, Rec. to 1.0 V)	25	ns

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.



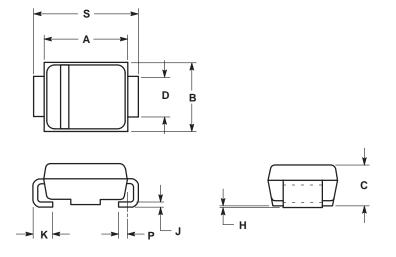
* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if applied V_R is sufficiently below rated V_R.





PACKAGE DIMENSIONS

SMB CASE 403A-03 ISSUE D



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.160	0.180	4.06	4.57
В	0.130	0.150	3.30	3.81
С	0.075	0.095	1.90	2.41
D	0.077	0.083	1.96	2.11
Н	0.0020	0.0060	0.051	0.152
J	0.006	0.012	0.15	0.30
К	0.030	0.050	0.76	1.27
Р	0.020 REF		0.51 REF	
S	0.205	0.220	5.21	5.59

<u>Notes</u>

<u>Notes</u>

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: ONIt@hibbertco.com Fax Response Line: 303–675–2167 or 800–344–3810 Toll Free USA/Canada

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor – European Support German Phone: (+1) 303–308–7140 (M–F 1:00pm to 5:00pm Munich Time)

- Email: ONlit-german@hibbertco.com French Phone: (+1) 303–308–7141 (M–F 1:00pm to 5:00pm Toulouse Time) Email: ONlit-french@hibbertco.com
- English Phone: (+1) 303–308–7142 (M–F 12:00pm to 5:00pm UK Time) Email: ONlit@hibbertco.com

EUROPEAN TOLL-FREE ACCESS*: 00-800-4422-3781 *Available from Germany, France, Italy, England, Ireland

CENTRAL/SOUTH AMERICA:

Spanish Phone: 303–308–7143 (Mon–Fri 8:00am to 5:00pm MST) Email: ONlit–spanish@hibbertco.com

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support Phone: 303–675–2121 (Tue–Fri 9:00am to 1:00pm, Hong Kong Time) Toll Free from Hong Kong & Singapore: 001–800–4422–3781 Email: ONlit–asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–8549 Phone: 81–3–5740–2745 Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.